

DATA SHEET

74LVC823A

9-bit D-type flip-flop with 5-volt tolerant inputs/outputs; positive-edge trigger (3-State)

Product specification

1998 Sep 24

9-bit D-type flip-flop with 5-volt tolerant inputs/outputs; positive-edge trigger (3-State)

74LVC823A

FEATURES

- 5-volt tolerant inputs/outputs, for interfacing with 5-volt logic
- Supply voltage range of 2.7V to 3.6V
- Complies with JEDEC standard no. 8-1A
- Inputs accept voltages up to 5.5V
- CMOS low power consumption
- Direct interface with TTL levels
- 9-bit positive edge-triggered register
- Independent register and 3-State buffer operation
- Flow-through pin-out architecture

DESCRIPTION

The 74LVC823A is a high performance, low-power, low-voltage Si-gate CMOS device and superior to most advanced CMOS compatible TTL families.

Inputs can be driven from either 3.3V or 5.0V devices. In 3-state operation, outputs can handle 5V. This feature allows the use of these devices as translators in a mixed 3.3V/5V environment.

The 74LVC823A is a 9-bit D-type flip-flop with common clock (CP), Clock Enable (\overline{CE}), Master Reset (\overline{MR}) and 3-State outputs for bus-oriented applications.

The nine flip-flops will store the state of their individual D-inputs that meet the set-up and hold times requirements on the LOW-to-HIGH CP transition provided \overline{CE} is LOW. When \overline{CE} is HIGH the flip-flops hold their data.

A LOW on \overline{MR} resets all flip-flops.

When \overline{OE} is LOW, the contents of the nine flip-flops is available at the outputs. When \overline{OE} is HIGH, the outputs go to the high impedance OFF-state. Operation of the \overline{OE} input does not affect the state of the flip-flops.

QUICK REFERENCE DATA

GND = 0 V; $T_{amb} = 25^{\circ}\text{C}$; $t_r = t_f \leq 2.5 \text{ ns}$

SYMBOL	PARAMETER	CONDITIONS	TYPICAL	UNIT
t_{PHL}/t_{PLH}	Propagation delay CP to Q_n	$C_L = 50 \text{ pF}$; $V_{CC} = 3.3 \text{ V}$	5.1	ns
	Propagation delay MR to Q_n		5.2	ns
f_{max}	Maximum clock frequency	$C_L = 50 \text{ pF}$; $V_{CC} = 3.3 \text{ V}$	150	MHz
C_I	Input capacitance		5.0	pF
C_{PD}	Power dissipation capacitance per flip-flop	Notes 1 and 2	27	pF

NOTES:

- C_{PD} is used to determine the dynamic power dissipation (P_D in μW)
 $P_D = C_{PD} \times V_{CC}^2 \times f_i + \sum (C_L \times V_{CC}^2 \times f_o)$ where:
 f_i = input frequency in MHz; C_L = output load capacity in pF;
 f_o = output frequency in MHz; V_{CC} = supply voltage in V;
 $\sum (C_L \times V_{CC}^2 \times f_o)$ = sum of the outputs.
- The condition is $V_I = \text{GND to } V_{CC}$

ORDERING INFORMATION

PACKAGES	TEMPERATURE RANGE	ORDERING CODE	PKG. DWG. #
24-Pin Plastic SO	-40°C to $+85^{\circ}\text{C}$	74LVC823A D	SOT137-1
24-Pin Plastic SSOP Type II	-40°C to $+85^{\circ}\text{C}$	74LVC823A DB	SOT340-1
24-Pin Plastic TSSOP Type I	-40°C to $+85^{\circ}\text{C}$	74LVC823A PW	SOT355-1

9-bit D-type flip-flop with 5-volt tolerant inputs/outputs; positive-edge trigger (3-State)

74LVC823A

PIN DESCRIPTION

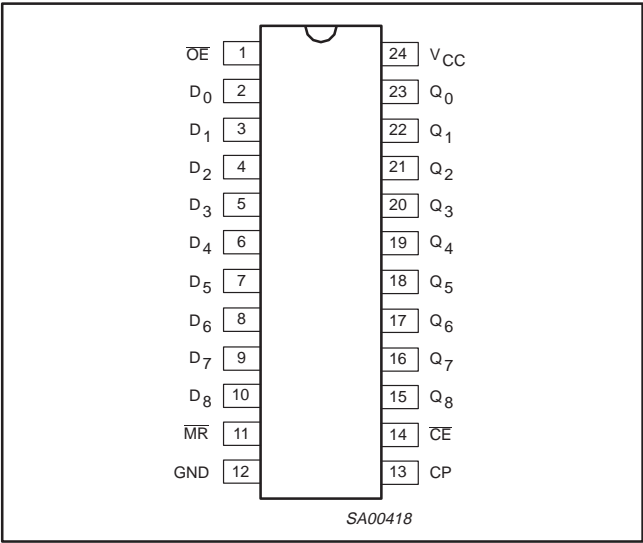
PIN NUMBER	SYMBOL	NAME AND FUNCTION
1	$\overline{\text{OE}}$	Output enable input (active LOW)
2, 3, 4, 5, 6, 7, 8, 9, 10	D ₀ to D ₈	Data inputs
11	$\overline{\text{MR}}$	Master reset (active LOW)
12	GND	Ground (0 V)
13	CP	Clock pulse (active rising)
14	$\overline{\text{CE}}$	Clock enable (active LOW)
23, 22, 21, 20, 19, 18, 17, 16, 15	Q ₀ to Q ₈	3-State flip-flop outputs
24	V _{CC}	Positive supply voltage

FUNCTION TABLE

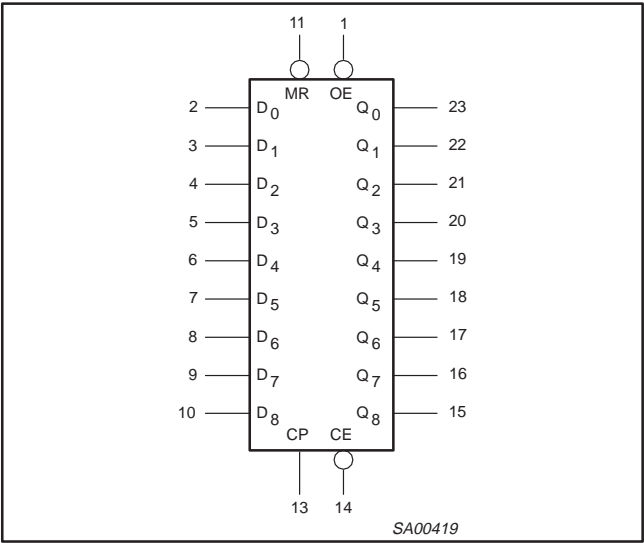
OPERATING MODES	INPUTS					INTERNAL FLIP-FLOPS	OUTPUTS
	$\overline{\text{OE}}$	$\overline{\text{MR}}$	$\overline{\text{CE}}$	CP	D _n		Q ₀ to Q ₈
Clear	L	L	X	X	X	L	L
Load and read register	L	H	L	↑	l	L	L
	L	H	L	↑	h	H	H
Load register and disable outputs	H	H	L	X	l	L	Z
	H	H	L	X	h	H	Z
Hold	L	H	H	NC	X	NC	NC

H = HIGH voltage level
h = HIGH voltage level one set-up time prior to the LOW-to-HIGH CP transition
L = LOW voltage level
l = LOW voltage level one set-up time prior to the LOW-to-HIGH CP transition
Z = high impedance OFF-state
↑ = LOW-to-HIGH clock transition
NC= no change

PIN CONFIGURATION



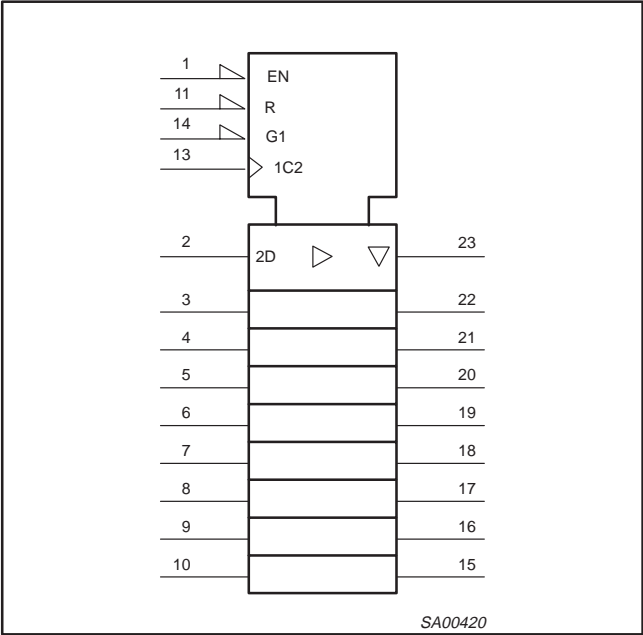
LOGIC SYMBOL



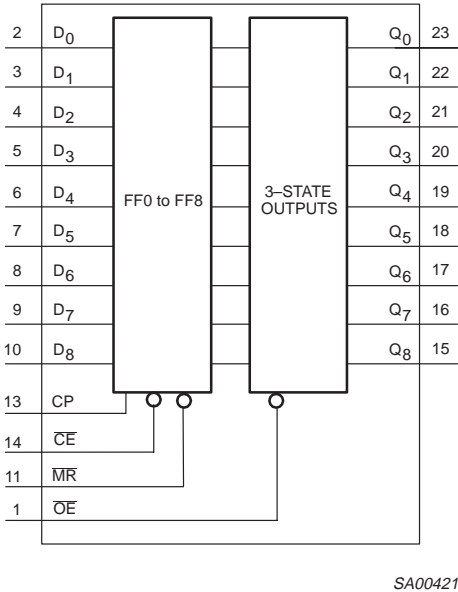
9-bit D-type flip-flop with 5-volt tolerant
inputs/outputs; positive-edge trigger (3-State)

74LVC823A

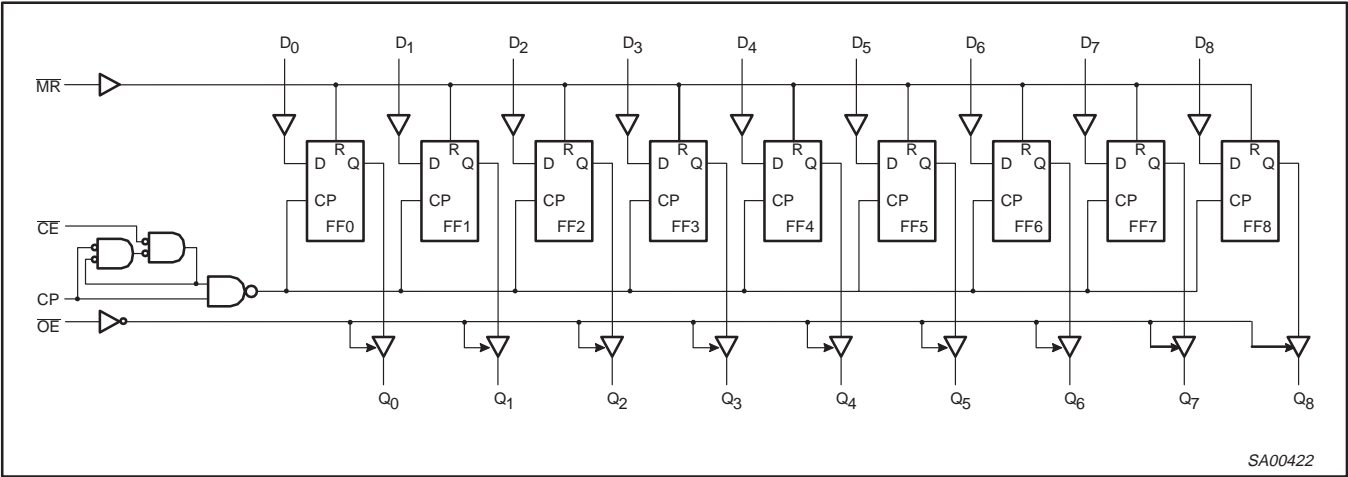
LOGIC SYMBOL (IEEE/IEC)



FUNCTIONAL DIAGRAM



LOGIC DIAGRAM



9-bit D-type flip-flop with 5-volt tolerant inputs/outputs; positive-edge trigger (3-State)

74LVC823A

RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	CONDITIONS	LIMITS		UNIT
			MIN	MAX	
V_{CC}	DC supply voltage (for max. speed performance)		2.7	3.6	V
	DC supply voltage (for low-voltage applications)		1.2	3.6	
V_I	DC Input voltage range		0	5.5	V
V_O	DC output voltage range; output HIGH or LOW state		0	V_{CC}	V
	DC output voltage range; output 3-State		0	5.5	
T_{amb}	Operating ambient temperature range in free-air		-40	+85	°C
t_r, t_f	Input rise and fall times	$V_{CC} = 1.2$ to $2.7V$ $V_{CC} = 2.7$ to $3.6V$	0 0	20 10	ns/V

ABSOLUTE MAXIMUM RATINGS¹

In accordance with the Absolute Maximum Rating System (IEC 134)

Voltages are referenced to GND (ground = 0V)

SYMBOL	PARAMETER	CONDITIONS	RATING	UNIT
V_{CC}	DC supply voltage		-0.5 to +6.5	V
I_{IK}	DC input diode current	$V_I < 0$	-50	mA
V_I	DC input voltage	Note 2	-0.5 to +6.5	V
I_{OK}	DC output diode current	$V_O > V_{CC}$ or $V_O < 0$	± 50	mA
V_O	DC output voltage; output HIGH or LOW state	Note 2	-0.5 to $V_{CC} + 0.5$	V
	DC output voltage; output 3-State	Note 2	-0.5 to 6.5	
I_O	DC output source or sink current	$V_O = 0$ to V_{CC}	± 50	mA
I_{GND}, I_{CC}	DC V_{CC} or GND current		± 100	mA
T_{stg}	Storage temperature range		-65 to +150	°C
P_{TOT}	Power dissipation per package			mW
	– plastic mini-pack (SO) – plastic shrink mini-pack (SSOP and TSSOP)	above +70°C derate linearly with 8 mW/K above +60°C derate linearly with 5.5 mW/K	500 500	

NOTES:

- Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

9-bit D-type flip-flop with 5-volt tolerant inputs/outputs; positive-edge trigger (3-State)

74LVC823A

DC ELECTRICAL CHARACTERISTICS

Over recommended operating conditions voltages are referenced to GND (ground = 0V)

SYMBOL	PARAMETER	TEST CONDITIONS	LIMITS			UNIT
			Temp = -40°C to +85°C			
			MIN	TYP ¹	MAX	
V _{IH}	HIGH level Input voltage	V _{CC} = 1.2V	V _{CC}			V
		V _{CC} = 2.7 to 3.6V	2.0			
V _{IL}	LOW level Input voltage	V _{CC} = 1.2V			GND	V
		V _{CC} = 2.7 to 3.6V			0.8	
V _{OH}	HIGH level output voltage	V _{CC} = 2.7V; V _I = V _{IH} or V _{IL} ; I _O = -12mA	V _{CC} - 0.5			V
		V _{CC} = 3.0V; V _I = V _{IH} or V _{IL} ; I _O = -100μA	V _{CC} - 0.2	V _{CC}		
		V _{CC} = 3.0V; V _I = V _{IH} or V _{IL} ; I _O = -18mA	V _{CC} - 0.6			
		V _{CC} = 3.0V; V _I = V _{IH} or V _{IL} ; I _O = -24mA	V _{CC} - 0.8			
V _{OL}	LOW level output voltage	V _{CC} = 2.7V; V _I = V _{IH} or V _{IL} ; I _O = 12mA			0.40	V
		V _{CC} = 3.0V; V _I = V _{IH} or V _{IL} ; I _O = 100μA			0.20	
		V _{CC} = 3.0V; V _I = V _{IH} or V _{IL} ; I _O = 24mA			0.55	
I _I	Input leakage current	V _{CC} = 3.6V; V _I = 5.5V or GND		± 0.1	± 5	μA
I _{OZ}	3-State output OFF-state current	V _{CC} = 3.6V; V _I = V _{IH} or V _{IL} ; V _O = 5.5V or GND		0.1	± 5	μA
I _{off}	Power off leakage supply	V _{CC} = 0.0V; V _I or V _O = 5.5V		0.1	± 10	μA
I _{CC}	Quiescent supply current	V _{CC} = 3.6V; V _I = V _{CC} or GND; I _O = 0		0.1	10	μA
ΔI _{CC}	Additional quiescent supply current per input pin	V _{CC} = 2.7V to 3.6V; V _I = V _{CC} - 0.6V; I _O = 0		5	500	μA

NOTES:

1. All typical values are at $V_{CC} = 3.3V$ and $T_{amb} = 25^\circ C$.
2. The specified overdrive current at the data input forces the data input to the opposite logic input state.

9-bit D-type flip-flop with 5-volt tolerant inputs/outputs; positive-edge trigger (3-State)

74LVC823A

AC CHARACTERISTICS

GND = 0V; $t_r = t_f \leq 2.5\text{ns}$; $C_L = 50\text{pF}$; $R_L = 500\Omega$; $T_{\text{amb}} = -40^\circ\text{C}$ to $+85^\circ\text{C}$.

SYMBOL	PARAMETER	WAVEFORM	LIMITS					UNIT
			V _{CC} = 3.3V ±0.3V			V _{CC} = 2.7V		
			MIN	TYP ¹	MAX	MIN	MAX	
t _{PHL} t _{PLH}	Propagation delay CP to Q _n	Figures 1, 4	1.5	5.1	8.0	1.5	8.9	ns
t _{PHL}	Propagation delay MR to Q _n	Figures 1, 4	1.5	5.2	7.9	1.5	8.8	ns
t _{PZH} t _{PZL}	3-State output enable time OE to Q _n	Figures 2, 4	1.5	5.2	7.65	1.5	8.65	ns
t _{PHZ} t _{PLZ}	3-State output disable time OE to Q _n	Figures 2, 4	1.5	3.8	6.0	1.5	7.1	ns
t _W	Clock pulse width HIGH or LOW	Figure 1	3.3			3.3		ns
t _W	Master Reset pulse width HIGH or LOW	Figure 1	3.3			3.3		ns
t _{SU}	Setup time D _n to CP	Figure 3	1.3			1.8		ns
t _{SU}	Setup time CE low before CP	Figure 3	1.8			1.0		ns
t _{rem}	Removal time MR	Figure 3	1.0			2.0		ns
t _h	Hold time HIGH or LOW D _n after CP	Figure 3	2.0			2.0		ns
t _h	Hold time CE LOW before CP	Figure 3	1.3			1.3		ns
f _{max}	Maximum clock pulse frequency	Figure 1	150	200		150		MHz

NOTE:

1. Unless otherwise stated, all typical values are at $V_{CC} = 3.3V$ and $T_{\text{amb}} = 25^\circ\text{C}$.

9-bit D-type flip-flop with 5-volt tolerant inputs/outputs; positive-edge trigger (3-State)

74LVC823A

AC WAVEFORMS

$V_M = 1.5\text{V}$ at $V_{CC} \geq 2.7\text{V}$; $V_M = 0.5 V_{CC}$ at $V_{CC} < 2.7\text{V}$.
 V_{OL} and V_{OH} are the typical output voltage drop that occur with the output load.
 $V_X = V_{OL} + 0.3\text{V}$ at $V_{CC} \geq 2.7\text{V}$; $V_X = V_{OL} + 0.1 V_{CC}$ at $V_{CC} < 2.7\text{V}$
 $V_Y = V_{OH} - 0.3\text{V}$ at $V_{CC} \geq 2.7\text{V}$; $V_Y = V_{OH} - 0.1 V_{CC}$ at $V_{CC} < 2.7\text{V}$

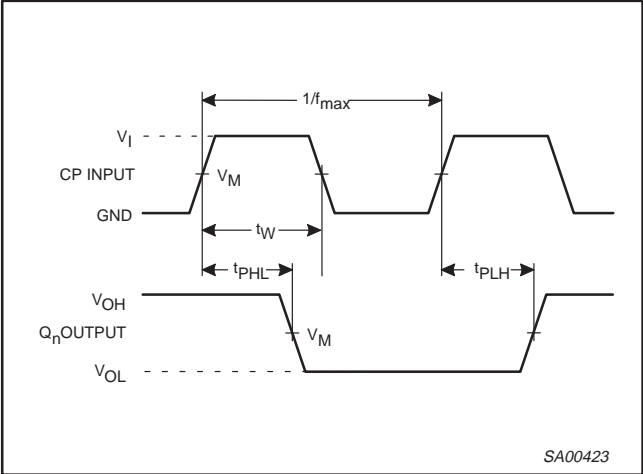


Figure 1. Clock (CP) to output (Qn) propagation delays, the clock pulse width and the maximum clock pulse frequency.

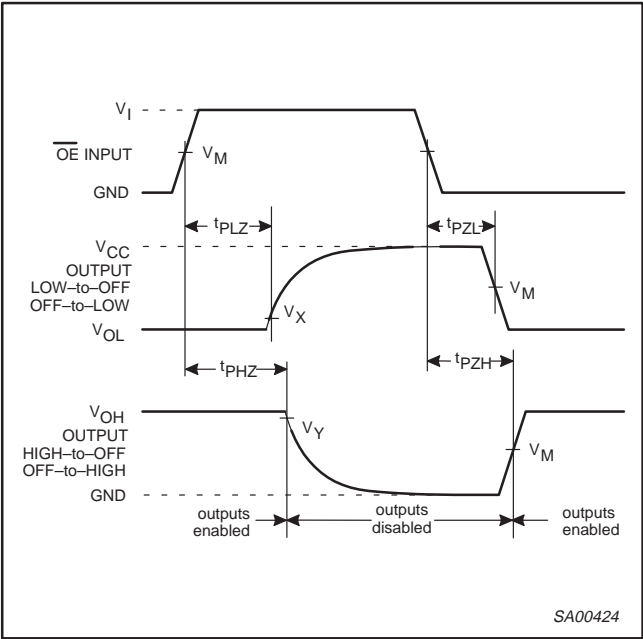


Figure 2. 3-State enable and disable times.

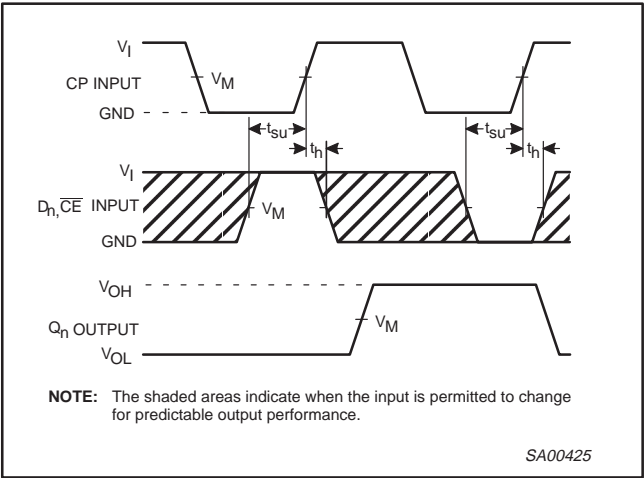


Figure 3. Data setup and hold times for the Dn input and CE input to the CP input.

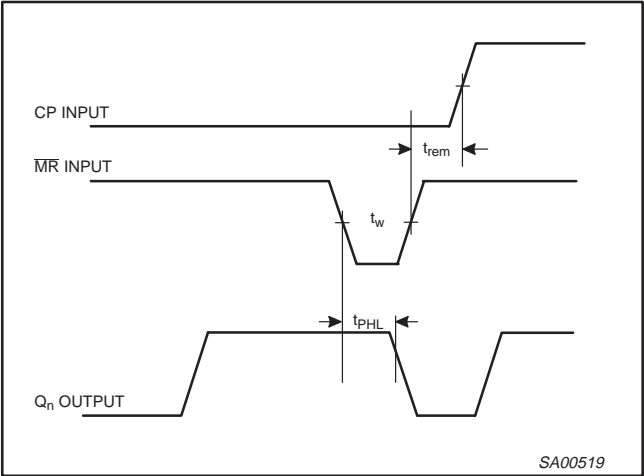


Figure 4. Master reset pulse width, master reset to clock removal time, master reset to output propagation delay.

TEST CIRCUIT

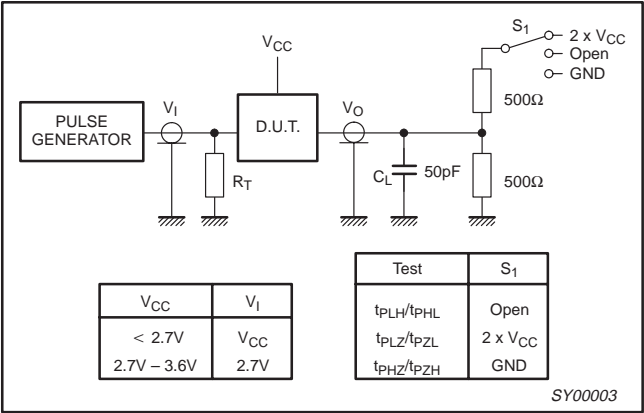


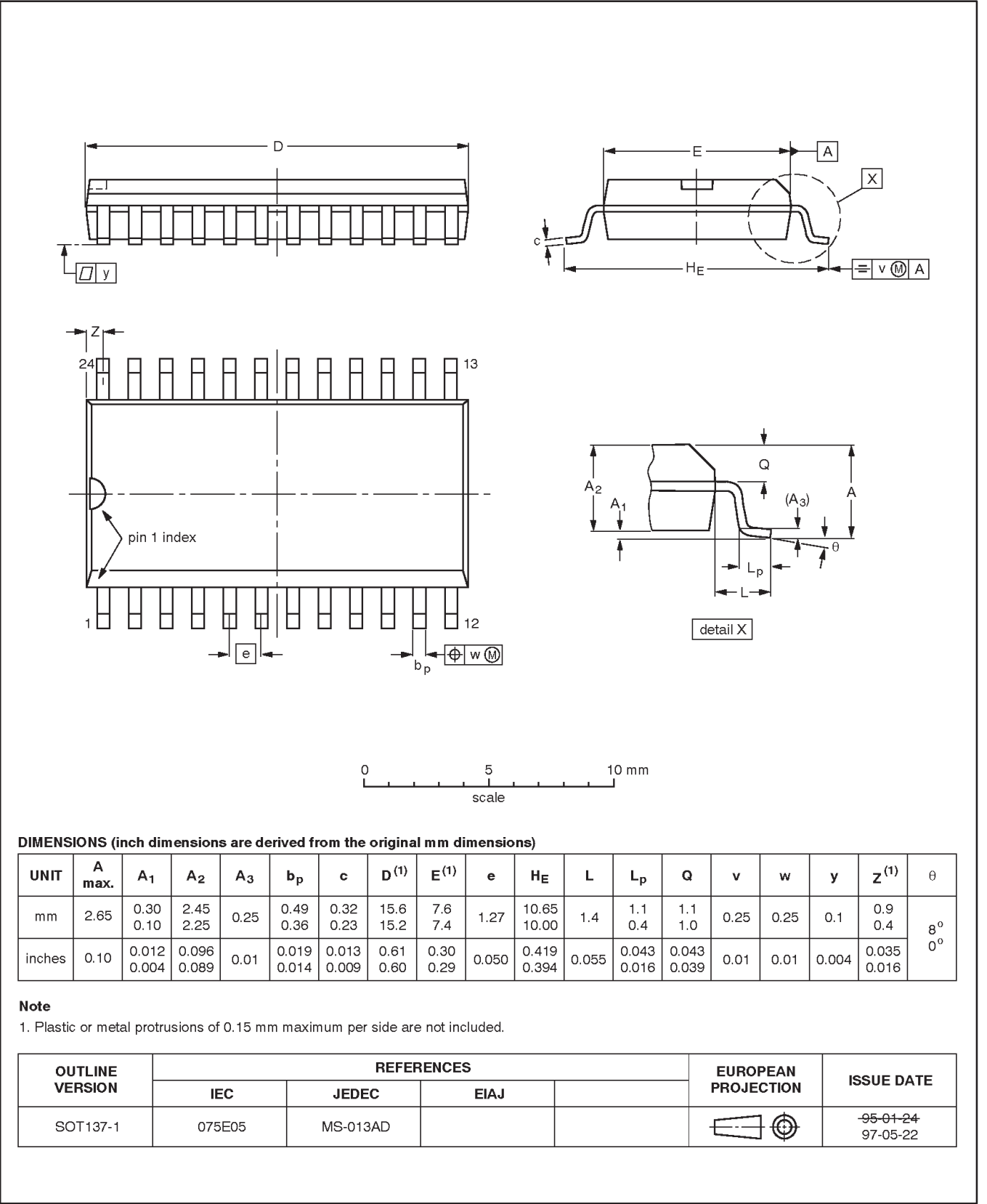
Figure 5. Load circuitry for switching times.

9-bit D-type flip-flop with 5-volt tolerant inputs/outputs; positive-edge trigger (3-State)

74LVC823A

SO24: plastic small outline package; 24 leads; body width 7.5 mm

SOT137-1

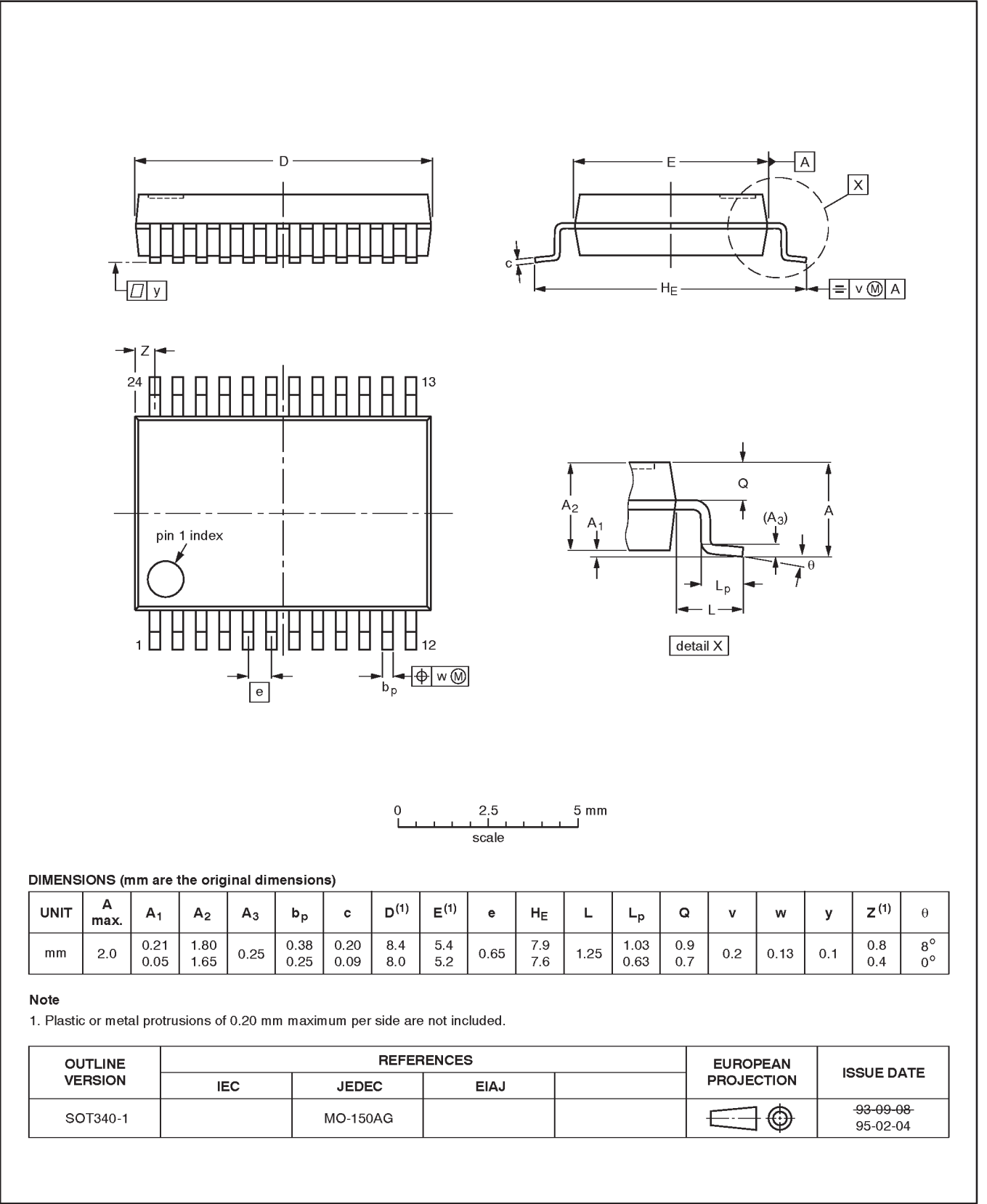


9-bit D-type flip-flop with 5-volt tolerant inputs/outputs; positive-edge trigger (3-State)

74LVC823A

SSOP24: plastic shrink small outline package; 24 leads; body width 5.3 mm

SOT340-1

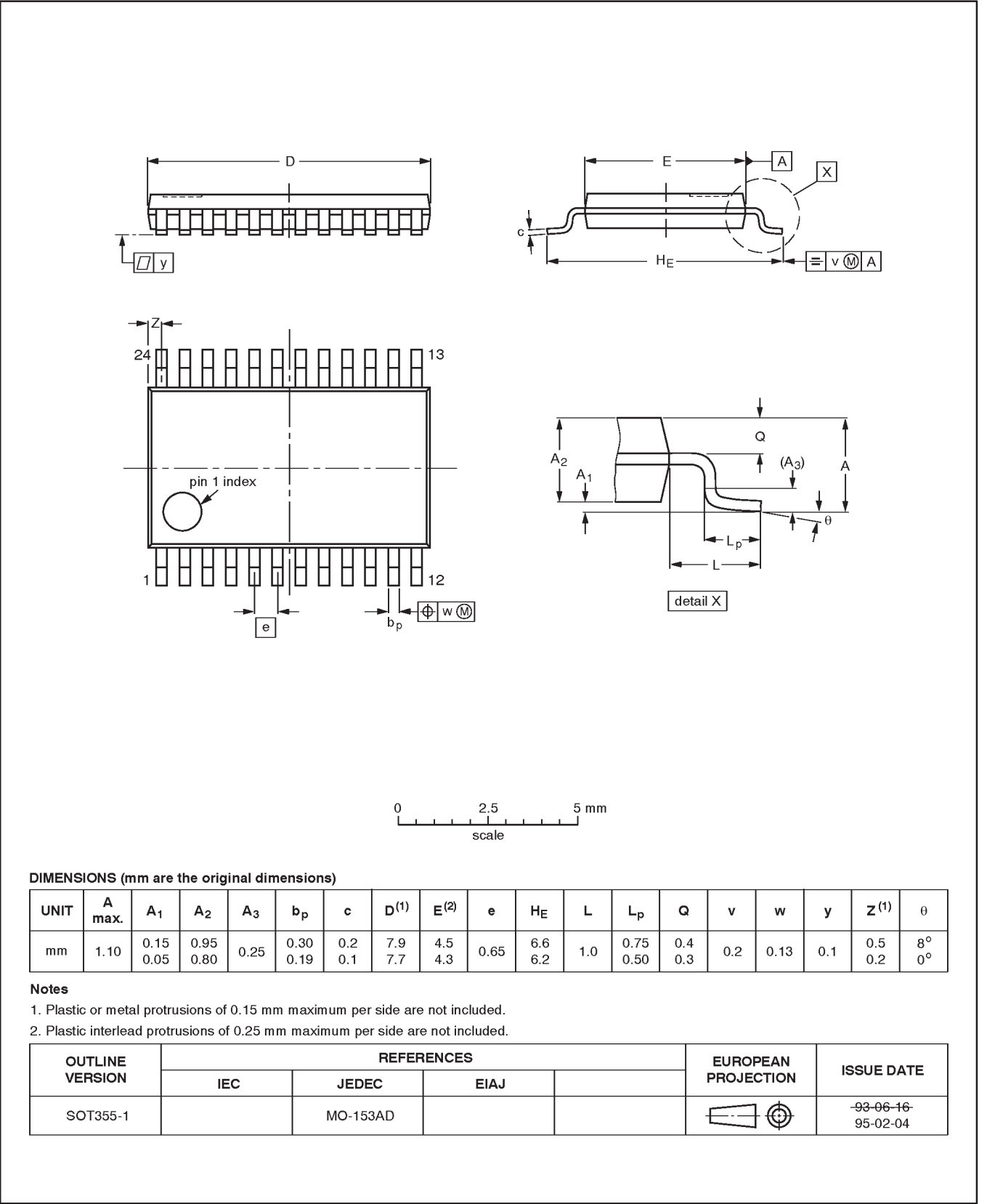


9-bit D-type flip-flop with 5-volt tolerant inputs/outputs; positive-edge trigger (3-State)

74LVC823A

TSSOP24: plastic thin shrink small outline package; 24 leads; body width 4.4 mm

SOT355-1



9-bit D-type flip-flop with 5-volt tolerant inputs/outputs; positive-edge trigger (3-State)

74LVC823A

Data sheet status

Data sheet status	Product status	Definition [1]
Objective specification	Development	This data sheet contains the design target or goal specifications for product development. Specification may change in any manner without notice.
Preliminary specification	Qualification	This data sheet contains preliminary data, and supplementary data will be published at a later date. Philips Semiconductors reserves the right to make changes at any time without notice in order to improve design and supply the best possible product.
Product specification	Production	This data sheet contains final specifications. Philips Semiconductors reserves the right to make changes at any time without notice in order to improve design and supply the best possible product.

[1] Please consult the most recently issued datasheet before initiating or completing a design.

Definitions

Short-form specification — The data in a short-form specification is extracted from a full data sheet with the same type number and title. For detailed information see the relevant data sheet or data handbook.

Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

Application information — Applications that are described herein for any of these products are for illustrative purposes only. Philips Semiconductors make no representation or warranty that such applications will be suitable for the specified use without further testing or modification.

Disclaimers

Life support — These products are not designed for use in life support appliances, devices or systems where malfunction of these products can reasonably be expected to result in personal injury. Philips Semiconductors customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Philips Semiconductors for any damages resulting from such application.

Right to make changes — Philips Semiconductors reserves the right to make changes, without notice, in the products, including circuits, standard cells, and/or software, described or contained herein in order to improve design and/or performance. Philips Semiconductors assumes no responsibility or liability for the use of any of these products, conveys no license or title under any patent, copyright, or mask work right to these products, and makes no representations or warranties that these products are free from patent, copyright, or mask work right infringement, unless otherwise specified.

Philips Semiconductors
811 East Arques Avenue
P.O. Box 3409
Sunnyvale, California 94088-3409
Telephone 800-234-7381

© Copyright Philips Electronics North America Corporation 1998
All rights reserved. Printed in U.S.A.

print code

Date of release: 08-98

Document order number:

9397-750-04583

Let's make things better.

This datasheet has been download from:

www.datasheetcatalog.com

Datasheets for electronics components.